











SN74AVC4T245

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SN74AVC4T245 Dual-Bit Bus Transceiver with Configurable Voltage Translation and 3-State Outputs

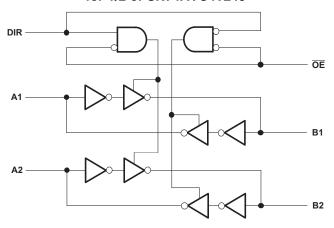
Features

- Control Inputs V_{IH}/V_{II} Levels Are Referenced to V_{CCA} Voltage
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant
- I_{off} Supports Partial Power-Down-Mode Operation
- Maximum Data Rates
 - 380 Mbps (1.8-V to 3.3-V Translation)
 - 200 Mbps (< 1.8-V to 3.3-V Translation)
 - 200 Mbps (Translate to 2.5 V or 1.8 V)
 - 150 Mbps (Translate to 1.5 V)
 - 100 Mbps (Translate to 1.2 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 8000-V Human-Body Model (A114-A)
 - 150-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

Applications

- Personal Electronics
- Industrial
- Enterprise
- Telecom

Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245



3 Description

This 4-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track $V_{\text{CCA}}.\ V_{\text{CCA}}$ accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.2 V to 3.6 V. The SN74AVC4T245 is optimized to operate with V_{CCA}/V_{CCB} set at 1.4 V to 3.6 V. It is operational with V_{CCA}/V_{CCB} as low as 1.2 V. This universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

The SN74AVC4T245 device is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ}.

The SN74AVC4T245 device is designed so that the control pins (1DIR, 2DIR, $1\overline{OE}$, and $2\overline{OE}$) are supplied by V_{CCA}.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both ports are in the highimpedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SOIC (16)	9.90 mm x 3.91 mm		
	TVSOP (16)	3.60 mm x 4.40 mm		
SN74AVC4T245	TSSOP (16)	5.00 mm x 4.40 mm		
	VQFN (16)	4.00 mm x 3.50 mm		
	UQFN (16)	2.60 mm x 1.80 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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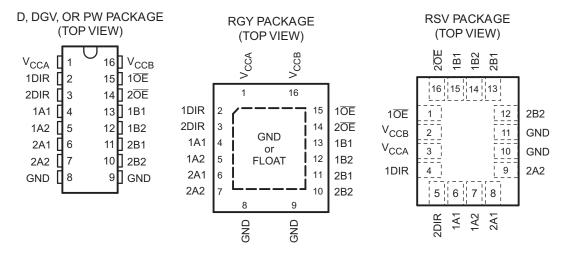
4 Revision History

Changes from Revision F (October 2014) to Revision G	Page
Changed Pin Functions table.	3
Changed Typical Application schematic.	14
Changes from Revision E (December 2011) to Revision F	Page
 Added Applications, Pin Configuration and Functions section, Handling Rating table, Thermal Information table, Feature Description section, Typical Characteristics section, Device Functional Modes, Application and 	
Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	1
Changes from Revision D (September 2007) to Revision E	Page
Fixed t _{PZI} V _{CCB} = 3.3 V parameter typographical error from 36.6 to 3.6.	7

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5 Pin Configuration and Functions



Pin Functions

PIN	NC).		
NAME	D, DGV, PW, RGY	RSV	TYPE	DESCRIPTION
1A1	4	6	I/O	Input/output 1A1. Referenced to V _{CCA} .
1A2	5	7	I/O	Input/output 1A2. Referenced to V _{CCA} .
1B1	13	15	I/O	Input/output 1B1. Referenced to V _{CCB} .
1B2	12	14	I/O	Input/output 1B2. Referenced to V _{CCB} .
1DIR	2	4	1	Direction-control input for '1' ports
1 OE	15	1	I	3-state output-mode enables. Pull $\overline{\text{OE}}$ high to place '1' outputs in 3-state mode. Referenced to V_{CCA} .
2A1	6	8	I/O	Input/output 2A1. Referenced to V _{CCA} .
2A2	7	9	I/O	Input/output 2A2. Referenced to V _{CCA} .
2B1	11	13	I/O	Input/output 2B1. Referenced to V _{CCB} .
2B2	10	12	I/O	Input/output 2B2. Referenced to V _{CCB} .
2DIR	3	5	1	Direction-control input for '2' ports
2 OE	14	16	I	3-state output-mode enables. Pull $\overline{\text{OE}}$ high to place '2' outputs in 3-state mode. Referenced to V_{CCA} .
GND	8, 9	10, 11	_	Ground
V _{CCA}	1	3	_	A-port power supply voltage. 1.2 V ≤ V _{CCA} ≤ 3.6 V
V _{CCB}	16	2	_	B-port power supply voltage. 1.2 V ≤ V _{CCB} ≤ 3.6 V

Product Folder Links: SN74AVC4T245



6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
$V_{CCA} V_{CCB}$	Supply voltage range		-0.5	4.6	V	
		I/O ports (A port)	-0.5	-0.5 4.6		
V_{I}	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	4.6	V	
		Control inputs	-0.5	4.6		
Vo	Voltage range applied to any output in the high-impedance or	A port	-0.5	4.6		
	Voltage range applied to any output in the high-impedance or power-off state $^{(2)}$	B port	-0.5	4.6	V	
.,	V-11	A port	-0.5	V _{CCA} + 0.5		
Vo	Voltage range applied to any output in the high or low state (2)(3)	B port	-0.5	V _{CCB} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
l _{OK}	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current	ı		±50	mA	
1	Continuous current through V _{CCA} , V _{CCB} , or GND		±100	mA		

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	ge	-65	150	°C
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾		8	kV
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)		1	KV
		Machine model (C101)		150	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

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⁽²⁾ The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (1)(2)(3)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT	
V_{CCA}	Supply voltage				1.2	3.6	V	
V _{CCB}	Supply voltage				1.2	3.6	V	
			1.2 V to 1.95 V		V _{CCI} × 0.65			
V_{IH}	High-level input voltage	Data inputs (4)	1.95 V to 2.7 V		1.6		V	
	input voltage		2.7 V to 3.6 V		2			
			1.2 V to 1.95 V			V _{CCI} × 0.35		
V_{IL}	Low-level input voltage	Data inputs ⁽⁴⁾	1.95 V to 2.7 V			0.7	V	
	input voltage		2.7 V to 3.6 V			8.0		
			1.2 V to 1.95 V		V _{CCA} × 0.65			
V_{IH}	High-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V		1.6		V	
	input voltage	(referenced to VCCA)	2.7 V to 3.6 V		2			
			1.2 V to 1.95 V			V _{CCA} × 0.35		
V_{IL}	Low-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V			0.7	V	
	input voitage	(referenced to ACCV)	2.7 V to 3.6 V			0.8		
VI	Input voltage				0	3.6	V	
.,	Outrot valtare	Active state			0	V _{cco}	V	
Vo	Output voltage	3-state			0	3.6	V	
				1.2 V		-3		
				1.4 V to 1.6 V		-6		
I_{OH}	High-level output of	current		1.65 V to 1.95 V		-8	mA	
				2.3 V to 2.7 V		-9		
				3 V to 3.6 V		-12		
				1.1 V to 1.2 V		3		
				1.4 V to 1.6 V		6		
I_{OL}	Low-level output co	urrent		1.65 V to 1.95 V		8	mA	
				2.3 V to 2.7 V		9		
				3 V to 3.6 V		12		
Δt/Δν	Input transition rise	e or fall rate				5	ns/V	
T _A	Operating free-air	temperature			-40	85	°C	

6.4 Thermal Information

				SN74AVC4T2	45					
	THERMAL METRIC ⁽¹⁾	D	DGV	PW	RGY	RSV	UNIT			
		16 PINS								
$R_{\theta JA}$	Junction-to-ambient thermal resistance	85.5	126.0	112.0	37.5	146.9				
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	46.9	50.8	46.8	54.5	53.6				
$R_{\theta JB}$	Junction-to-board thermal resistance	43.0	57.7	57.1	15.6	75.6	°C/W			
ΨЈТ	Junction-to-top characterization parameter	13.4	5.7	5.7	0.5	13.5	· C/vv			
ΨЈВ	Junction-to-board characterization parameter	42.7	57.2	56.5	15.8	75.6				
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	_	_	3.5	_				

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

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V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs* (SCBA004).
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V



6.5 Electrical Characteristics (1)(2)

over recommended operating free-air temperature range (unless otherwise noted)

DAI	AMETER	TEST CONDI	TIONS	v	v	T,	4 = 25°C		-40°C to 8	5°C	LINUT	
PAI	RAMETER	TEST CONDI	IIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNIT	
		$I_{OH} = -100 \ \mu A$		1.2 V to 3.6 V	1.2 V to 3.6 V				V _{CCO} - 0.2			
		$I_{OH} = -3 \text{ mA}$		1.2 V	1.2 V		0.95				•	
\/		$I_{OH} = -6 \text{ mA}$		1.4 V	1.4 V				1.05		V	
V_{OH}		$I_{OH} = -8 \text{ mA}$	$V_I = V_{IH}$	1.65 V	1.65 V				1.2		V	
		$I_{OH} = -9 \text{ mA}$		2.3 V	2.3 V				1.75			
		$I_{OH} = -12 \text{ mA}$		3 V	3 V				2.3			
		$I_{OL} = 100 \mu A$		1.2 V to 3.6 V	1.2 V to 3.6 V					0.2		
V		$I_{OL} = 3 \text{ mA}$		1.2 V	1.2 V		0.25					
		$I_{OL} = 6 \text{ mA}$	$V_I = V_{IL}$	1.4 V	1.4 V					0.35	V	
V_{OL}		$I_{OL} = 8 \text{ mA}$	VI = VIL	1.65 V	1.65 V					0.45	V	
		$I_{OL} = 9 \text{ mA}$		2.3 V	2.3 V					0.55		
		I _{OL} = 12 mA		3 V	3 V					0.7		
II	Control inputs	V _I = V _{CCA} or GND		1.2 V to 3.6 V	1.2 V to 3.6 V		±0.025	±0.25		±1	μΑ	
	A D	V == V = 0.15 0.0V		0 V	0 V to 3.6 V		±0.1	±1		±5		
l _{off}	A or B port	$V_1 \text{ or } V_0 = 0 \text{ to } 3.6$	V	0 V to 3.6 V	0 V		±0.1	±1		±5	μA	
I _{OZ}	A or B port	$V_O = V_{CCO}$ or GND $V_I = V_{CCI}$ or GND,	OE = V _{IH}	3.6 V	3.6 V		±0.5	±2.5		±5	μΑ	
				1.2 V to 3.6 V	1.2 V to 3.6 V					8		
I_{CCA}		$V_I = V_{CCI}$ or GND,	I _O = 0	0 V	0 V to 3.6 V					-2	μA	
				0 V to 3.6 V	0 V					8		
				1.2 V to 3.6 V	1.2 V to 3.6 V					8		
I_{CCB}		$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	0 V	0 V to 3.6 V					8	μΑ	
				0 V to 3.6 V	0 V					-2	•	
I _{CCA} +	- I _{CCB}	$V_I = V_{CCI}$ or GND,	I _O = 0	1.2 V to 3.6 V	1.2 V to 3.6 V					16	μΑ	
C _i	Control inputs	V _I = 3.3 V or GND		3.3 V	3.3 V		3.5			4.5	pF	
C _{io}	A or B port	$V_O = 3.3 \text{ V or GNE}$)	3.3 V	3.3 V		6			7	pF	

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \text{ is the } V_{CC} \text{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \text{ is the } V_{CC} \text{ associated with the input port.} \\ \end{array}$

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6.6 Operating Characteristics

 $T_{\Delta} = 25^{\circ}C$

F	PARAME	TER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.2 V	V _{CCA} = V _{CCB} = 1.5 V	V _{CCA} = V _{CCB} = 1.8 V	$V_{CCA} = V_{CCB} = 2.5 V$	V _{CCA} = V _{CCB} = 3.3 V	UNIT	
	A to B	Outputs enabled		1	1	1	1.5	2		
C _{pdA} (1)		Outputs disabled	$C_L = 0$,	1	1	1	1	1	~F	
	B to A	Outputs enabled	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	12	12.5	13	14	15	pF	
		Outputs disabled		1	1	1	1	1		
	A to B	Outputs enabled	$C_L = 0$,	12	12.5	13	14	15		
C (1)		Outputs disabled		1	1	1	1	1	pF	
C _{pdB} (1)	B to A	Outputs enabled	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	1	1	1	1	2	þΓ	
	D 10 A	Outputs disabled		1	1	1	1	1		

⁽¹⁾ Power dissipation capacitance per transceiver

6.7 Switching Characteristics: $V_{CCA} = 1.2 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.2 \text{ V}$ (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V ± 0.1 V	V _{CCB} = 1.8 V ± 0.15 V	V _{CCB} = 2.5 V ± 0.2 V	V _{CCB} = 3.3 V ± 0.3 V	UNIT	
	(INFOT)	(0011-01)	TYP	TYP	TYP	TYP	TYP		
t _{PLH}	А	В	3.4	2.9	2.7	2.6	2.8	20	
t _{PHL}	A	Ь	3.4	2.9	2.7	2.6	2.8	ns	
t _{PLH}	В	A	3.6	3.1	2.8	2.6	2.6	ns	
t _{PHL}	Ь	A	3.6	3.1	2.8	2.6	2.6	110	
t _{PZH}	ŌĒ	^	5.6	4.7	4.3	3.9	3.7	20	
t _{PZL}	OE	A	5.6	4.7	4.3	3.9	3.7	ns	
t _{PZH}	ŌĒ	В	5	4.3	3.9	3.6	3.6	20	
t _{PZL}	OE	Б	5	4.3	3.9	3.6	3.6	ns	
t _{PHZ}	ŌĒ	A	6.2	5.2	5.2	4.3	4.8	ns	
t _{PLZ}	OE .	A	6.2	5.2	5.2	4.3	4.8		
t _{PHZ}	ŌĒ	В	5.9	5.1	5	4.7	5.5	20	
t _{PLZ}	OE .	В	5.9	5.1	5	4.7	5.5	ns	

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6.8 Switching Characteristics: $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$ (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1	1.5 V I V	V _{CCB} = 1.8 V ± 0.15 V		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		UNIT	
		(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	А	В	3.2	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	no	
t _{PHL}	A	Б	3.2	0.3	6.3	0.3	5.2	0.4	4.2	0.4	4.2	ns	
t _{PLH}	В	^	3.3	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	20	
t _{PHL}	В	Α	3.3	0.7	6.3	0.5	6	0.4	5.7	0.3	5.6	ns	
t _{PZH}	ŌĒ	Α	4.9	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	no	
t _{PZL}	ÜE	OE	A	4.9	1.4	9.6	1.1	9.5	0.7	9.4	0.4	9.4	ns
t _{PZH}	ŌĒ	В	4.5	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	20	
t _{PZL}	OE	Б	4.5	1.4	9.6	1.1	7.7	0.9	5.8	0.9	5.6	ns	
t _{PHZ}	ŌĒ	Α	5.6	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	20	
t _{PLZ}	OE	A	5.6	1.8	10.2	1.5	10.2	1.3	10.2	1.6	10.2	ns	
t _{PHZ}	ŌĒ	В	5.2	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	no	
t _{PLZ}	OE	В	5.2	1.9	10.3	1.9	9.1	1.4	7.4	1.2	7.6	ns	

6.9 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT
	(INPOT)	(OUTPUT)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	В	2.9	0.1	6	0.1	4.9	0.1	3.9	0.3	3.9	20
t _{PHL}	A	Б	2.9	0.1	6	0.1	4.9	0.1	3.9	0.3	3.9	ns
t _{PLH}	В	Α	3	0.6	5.3	0.5	4.9	0.3	4.6	0.3	4.5	5
t _{PHL}	Ь	A	3	0.6	5.3	0.5	4.9	0.3	4.6	0.3	4.5	ns
t _{PZH}	ŌĒ	Α	4.4	1	7.4	1	7.3	0.6	7.3	0.4	7.2	ns
t _{PZL}	OE	A	4.4	1	7.4	1	7.3	0.6	7.3	0.4	7.2	115
t _{PZH}	ŌE	В	4.1	1.2	9.2	1	7.4	0.8	5.3	0.8	4.6	
t _{PZL}	OE	Б	4.1	1.2	9.2	1	7.4	0.8	5.3	0.8	4.6	ns
t _{PHZ}	ŌĒ	Α	5.4	1.6	8.6	1.8	8.7	1.3	8.7	1.6	8.7	5
t _{PLZ}	OE .	A	5.4	1.6	8.6	1.8	8.7	1.3	8.7	1.6	8.7	ns
t _{PHZ}	ŌĒ	В	5	1.7	9.9	1.6	8.7	1.2	6.9	1	6.9	
t _{PLZ}	UE	В	5	1.7	9.9	1.6	8.7	1.2	6.9	1	6.9	ns

Product Folder Links: SN74AVC4T245

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6.10 Switching Characteristics: $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	В	2.8	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	20
t _{PHL}	A	Ь	2.8	0.1	5.7	0.1	4.6	0.2	3.5	0.1	3.6	ns
t _{PLH}	В	Α	2.7	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	20
t _{PHL}	D	A	2.7	0.6	4.2	0.4	3.9	0.2	3.4	0.2	3.3	ns
t _{PZH}	ŌĒ	Α	4	0.7	6.5	0.7	5.2	0.6	4.8	0.4	4.8	ns
t_{PZL}	OE	A	4	0.7	6.5	0.7	5.2	0.6	4.8	0.4	4.8	115
t _{PZH}	ŌĒ	В	3.8	0.9	8.8	0.8	7	0.6	4.8	0.6	4	20
t _{PZL}	OE	Ь	3.8	0.9	8.8	0.8	7	0.6	4.8	0.6	4	ns
t _{PHZ}	ŌĒ	Α	4.7	1	8.4	1	8.4	1	6.2	1	6.6	20
t_{PLZ}	OE	A	4.7	1	8.4	1	8.4	1	6.2	1	6.6	ns
t _{PHZ}	ŌĒ	В	4.5	1.5	9.4	1.3	8.2	1.1	6.2	0.9	5.2	nc
t _{PLZ}	OE	В	4.5	1.5	9.4	1.3	8.2	1.1	6.2	0.9	5.2	ns

6.11 Switching Characteristics: $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$

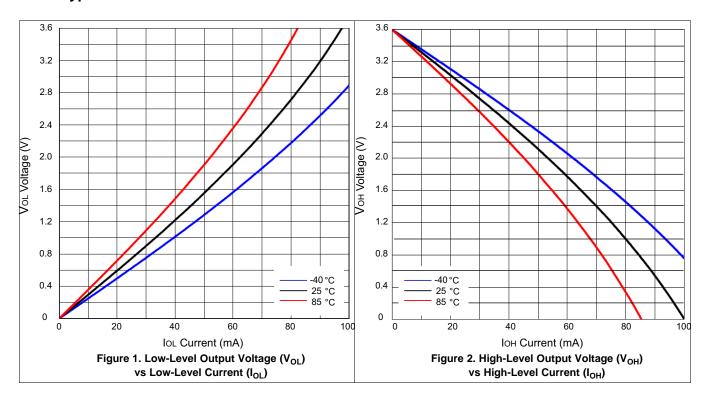
over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (see Figure 3)

PARAMETER	FROM (INPUT)	TO	V _{CCB} = 1.2 V	V _{CCB} = ± 0.1		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V _{CCB} = ± 0.3		UNIT
	(INPUT)	(OUTPUT)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	В	2.9	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	
t _{PHL}	A	В	2.9	0.1	5.6	0.1	4.5	0.1	3.3	0.1	2.9	ns
t _{PLH}	В	Α	2.6	0.6	4.2	0.4	3.4	0.2	3	0.1	2.8	no
t _{PHL}	ь	A	2.6	0.6	4.2	0.4	3.4	0.2	3	0.1	2.8	ns
t _{PZH}	ŌĒ	А	3.8	0.6	8.7	0.6	5.2	0.6	3.8	0.4	3.8	no
t _{PZL}	OE	A	3.8	0.6	8.7	0.6	5.2	0.6	3.8	0.4	3.8	ns
t _{PZH}	ŌĒ	В	3.7	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	
t _{PZL}	OE	В	3.7	0.8	8.7	0.6	6.8	0.5	4.7	0.5	3.8	ns
t _{PHZ}	ŌĒ	А	4.8	0.7	9.3	0.7	8.3	0.7	5.6	0.7	6.6	no
t _{PLZ}	OE .	A	4.8	0.7	9.3	0.7	8.3	0.7	5.6	0.7	6.6	ns
t _{PHZ}	ŌĒ	В	5.3	1.4	9.3	1.2	8.1	1	6.4	0.8	6.2	
t _{PLZ}	UE	В	5.3	1.4	9.3	1.2	8.1	1	6.4	0.8	6.2	ns

Product Folder Links: SN74AVC4T245



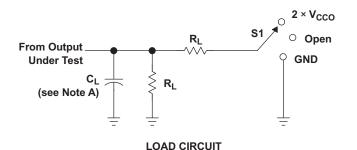
6.12 Typical Characteristics



 V_{CCA}



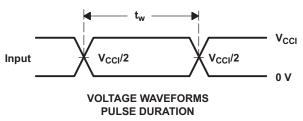
Parameter Measurement Information



TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	2 × V _{CCO}
t _{PHZ} /t _{PZH}	GND

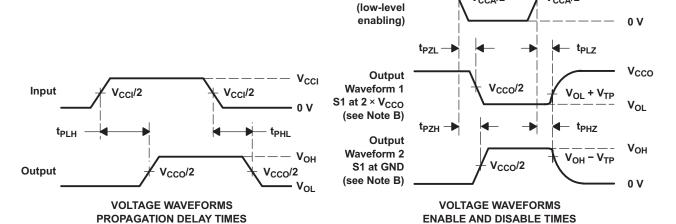
 C_L R_L V_{TP} 15 pF **2 k**Ω 0.1 V

 V_{CCO} 1.2 V 1.5 V ± 0.1 V 15 pF **2** kΩ 0.1 V 0.15 V 1.8 V ± 0.15 V 15 pF **2** kΩ 0.15 V $2.5~V\pm0.2~V$ 15 pF **2 k**Ω 3.3 V \pm 0.3 V 15 pF **2 k**Ω 0.3 V



V_{CCA}/2

V_{CCA}/2



Output Control

NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, $Z_0 = 50 \Omega$, $dv/dt \ge 1 V/ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

Figure 3. Load and Circuit and Voltage Waveforms

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8 Detailed Description

8.1 Overview

The SN74AVC4T245 is a 4-bit, dual-supply noninverting bidirectional voltage level translation device. Ax pins and control pins (1DIR, 2DIR,1OE, and 2OE) are supported by V_{CCA} , and Bx pins are supported by V_{CCB} . The A port is able to accept I/O voltages ranging from 1.2 V to 3.6 V, while the B port can accept I/O voltages from 1.2 V to 3.6 V. A high on DIR allows data transmission from Ax to Bx and a low on DIR allows data transmission from Bx to Ax when \overline{OE} is set to low. When \overline{OE} is set to high, both Ax and Bx pins are in the high-impedance state.

8.2 Functional Block Diagram

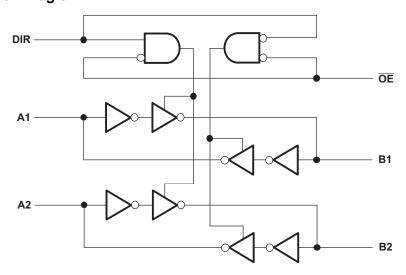


Figure 4. Logic Diagram (Positive Logic) for 1/2 of SN74AVC4T245

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8.3 Feature Description

8.3.1 Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range

Both V_{CCA} and V_{CCB} can be supplied at any voltage between 1.2 V and 3.6 V; thus, making the device suitable for translating between any of the low voltage nodes (1.2 V, 1.8 V, 2.5 V, and 3.3 V).

8.3.2 Supports High Speed Translation

The SN74AVC4T245 device can support high data rate applications. The translated signal data rate can be up to 380 Mbps when the signal is translated from 1.8 V to 3.3 V.

8.3.3 I_{off} Supports Partial-Power-Down Mode Operation

loff will prevent backflow current by disabling I/O output circuits when device is in partial-power-down mode.

8.4 Device Functional Modes

Table 1. Function Table (Each 2-Bit Section)⁽¹⁾

CONTRO	L INPUTS	OUTPUT O	CIRCUITS	ODEDATION
ŌĒ	DIR	DIR A PORT B PORT		OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	Н	Hi-Z	Enabled	A data to B bus
Н	Χ	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os are always active.

Product Folder Links: SN74AVC4T245



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74AVC4T245 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The SN74AVC4T245 device is ideal for use in applications where a push-pull driver is connected to the data I/Os. The max data rate can be up to 380 Mbps when device translates a signal from 1.8 V to 3.3 V.

9.2 Typical Application

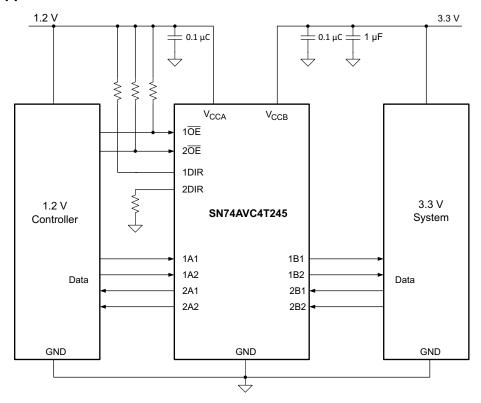


Figure 5. Typical Application Diagram

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Typical Application (continued)

9.2.1 Design Requirements

For the design example shown in *Typical Application*, use the parameters listed in Table 2.

Table 2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.2 V to 3.6 V
Output voltage range	1.2 V to 3.6 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the SN74AVC4T245 device to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the SN74AVC4T245 device is driving to determine the output voltage range.

9.2.3 Application Curves

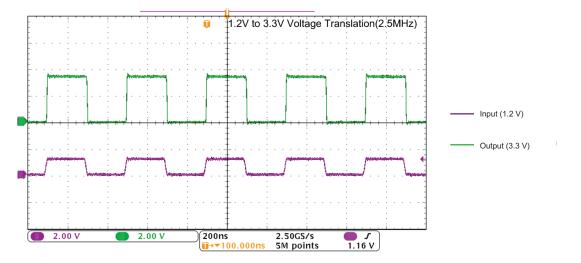


Figure 6. Translation Up (1.2 V to 3.3 V) at 2.5 MHz



10 Power Supply Recommendations

The SN74AVC4T245 device uses two separate configurable power-supply rails, V_{CCA} and V_{CCB} . V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V and V_{CCB} accepts any supply voltage from 1.2 V to 3.6 V. The A port and B port are designed to track V_{CCA} and V_{CCB} respectively allowing for low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V and 3.3-V voltage nodes.

The output-enable (\overline{OE}) input circuit is designed so that it is supplied by V_{CCA} and when the \overline{OE} input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the \overline{OE} input pin must be tied to V_{CCA} through a pullup resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pullup resistor to V_{CCA} is determined by the current-sinking capability of the driver.

11 Layout

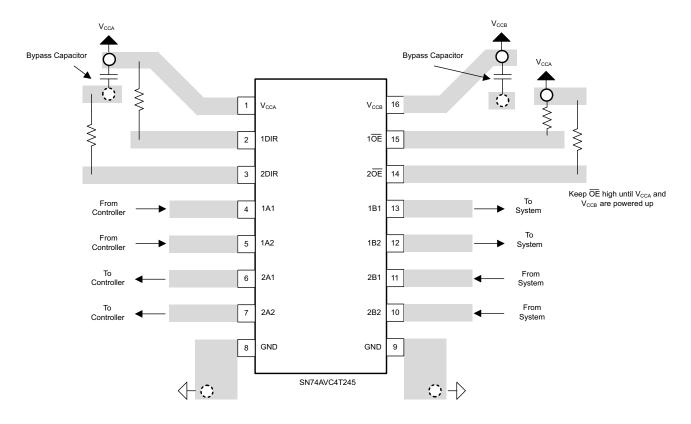
11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Place pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals, depending on the system requirements.

11.2 Layout Example





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12 Device and Documentation Support

12.1 Trademarks

All trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

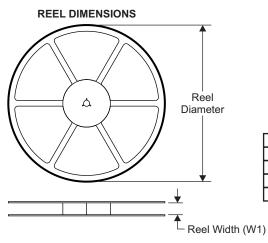
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

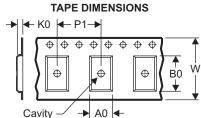
Product Folder Links: SN74AVC4T245



13.1 Package Materials Information

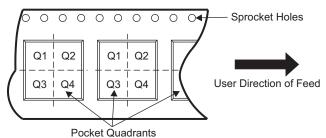
13.1.1 Tape and Reel Information





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

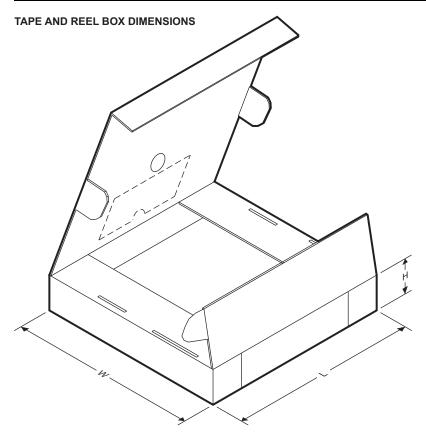
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC4T245DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AVC4T245DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74AVC4T245PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC4T245RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN74AVC4T245RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN74AVC4T245RSVR	UQFN	RSV	16	3000	180.0	12.4	2.1	2.9	0.75	4.0	12.0	Q1

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC4T245DGVR	TVSOP	DGV	16	2000	367.0	367.0	35.0
SN74AVC4T245DR	SOIC	D	16	2500	333.2	345.9	28.6
SN74AVC4T245PWR	TSSOP	PW	16	2000	367.0	367.0	35.0
SN74AVC4T245RGYR	VQFN	RGY	16	3000	367.0	367.0	35.0
SN74AVC4T245RGYR	VQFN	RGY	16	3000	355.0	350.0	50.0
SN74AVC4T245RSVR	UQFN	RSV	16	3000	203.0	203.0	35.0





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
74AVC4T245DGVRE4	ACTIVE	TVSOP	DGV	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
74AVC4T245RGYRG4	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WT245	Samples
74AVC4T245RSVR-NT	ACTIVE	UQFN	RSV	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWU	Samples
74AVC4T245RSVRG4	ACTIVE	UQFN	RSV	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWU	Samples
HPA00719RSVR	ACTIVE	UQFN	RSV	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWU	Samples
SN74AVC4T245D	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC4T245	Samples
SN74AVC4T245DGVR	ACTIVE	TVSOP	DGV	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC4T245	Samples
SN74AVC4T245DRE4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC4T245	Samples
SN74AVC4T245DT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVC4T245	Samples
SN74AVC4T245PW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWE4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWRE4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWT	ACTIVE	TSSOP	PW	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWTE4	ACTIVE	TSSOP	PW	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245PWTG4	ACTIVE	TSSOP	PW	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	WT245	Samples
SN74AVC4T245RGYR	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	WT245	Samples
SN74AVC4T245RSVR	ACTIVE	UQFN	RSV	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWU	Samples

PACKAGE OPTION ADDENDUM



10-Dec-2020

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74AVC4T245:

Automotive: SN74AVC4T245-Q1

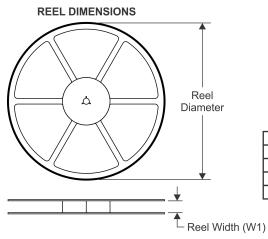
NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVC4T245RSVR-NT	UQFN	RSV	16	3000	180.0	8.4	2.0	2.8	0.7	4.0	8.0	Q1
74AVC4T245RSVR-NT	UQFN	RSV	16	3000	180.0	9.5	2.1	2.9	0.75	4.0	8.0	Q1
SN74AVC4T245DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AVC4T245DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74AVC4T245PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC4T245PWT	TSSOP	PW	16	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC4T245RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
SN74AVC4T245RSVR	UQFN	RSV	16	3000	178.0	13.5	2.1	2.9	0.75	4.0	12.0	Q1
SN74AVC4T245RSVR	UQFN	RSV	16	3000	180.0	12.4	2.1	2.9	0.75	4.0	12.0	Q1



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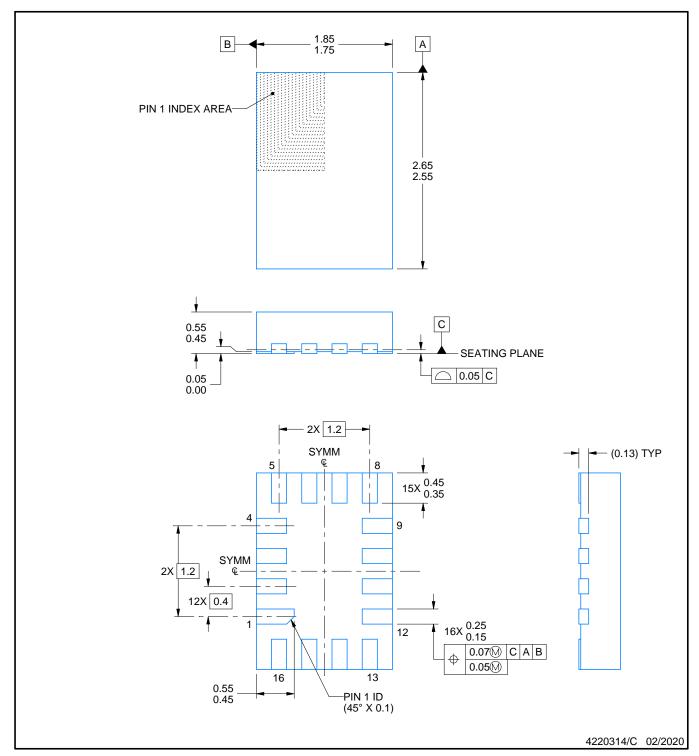


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
201.00	· uomuge .) pe	· working - running	•	• •	y ()	,	,
74AVC4T245RSVR-NT	UQFN	RSV	16	3000	200.0	183.0	25.0
74AVC4T245RSVR-NT	UQFN	RSV	16	3000	189.0	185.0	36.0
SN74AVC4T245DGVR	TVSOP	DGV	16	2000	853.0	449.0	35.0
SN74AVC4T245DR	SOIC	D	16	2500	340.5	336.1	32.0
SN74AVC4T245PWR	TSSOP	PW	16	2000	853.0	449.0	35.0
SN74AVC4T245PWT	TSSOP	PW	16	250	853.0	449.0	35.0
SN74AVC4T245RGYR	VQFN	RGY	16	3000	853.0	449.0	35.0
SN74AVC4T245RSVR	UQFN	RSV	16	3000	189.0	185.0	36.0
SN74AVC4T245RSVR	UQFN	RSV	16	3000	200.0	183.0	25.0



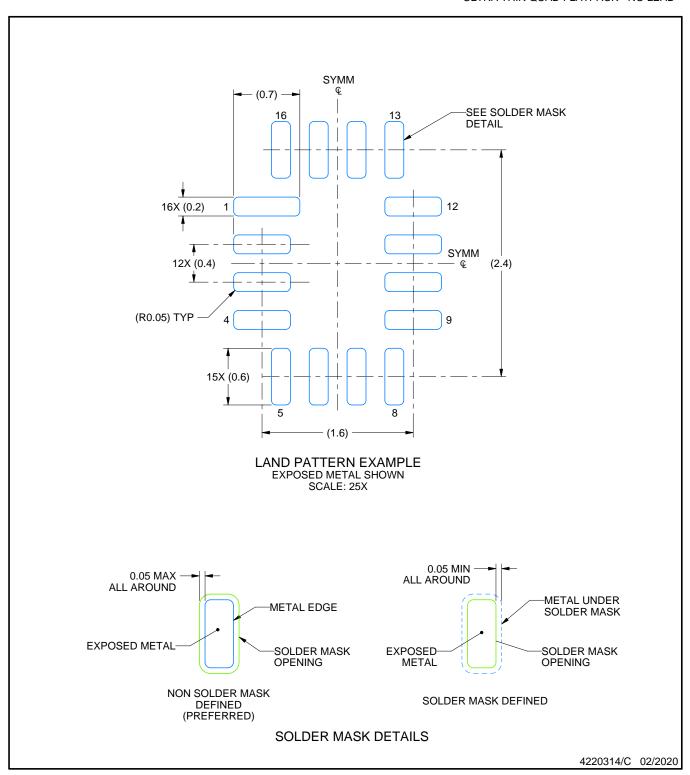
ULTRA THIN QUAD FLATPACK - NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.



ULTRA THIN QUAD FLATPACK - NO LEAD

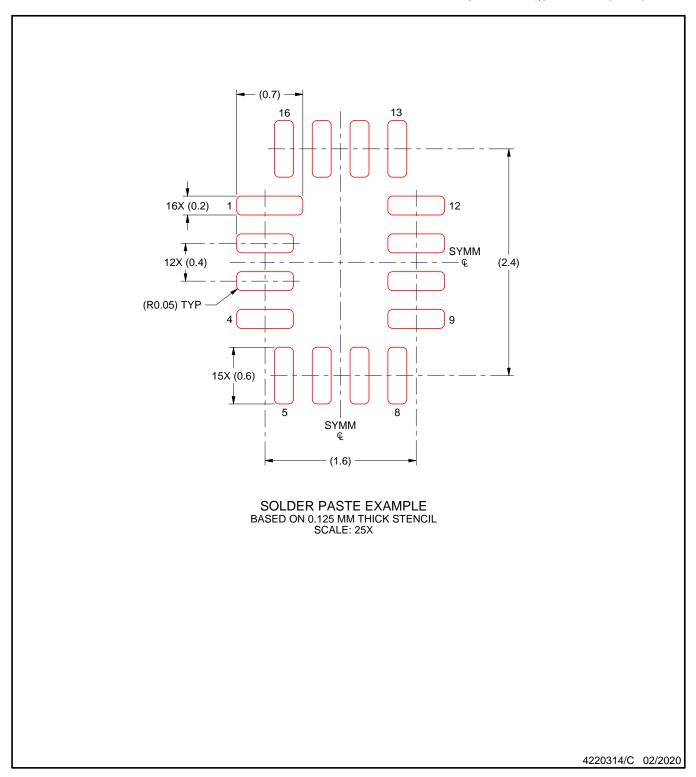


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



ULTRA THIN QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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